

SANYO	No.1289C	2SA1347/2SC3401
		PNP/NPN Epitaxial Planar Silicon Transistors Switching Applications (with Bias Resistance)

Applications

Switching circuit, inverter, interface circuit, driver

Features

- Built-in bias resistor ($R_1=46k\Omega$, $R_2=23k\Omega$).
- Small-sized package (SPA).

(): 2SA1347

Absolute Maximum Ratings/ $T_a=25^\circ\text{C}$

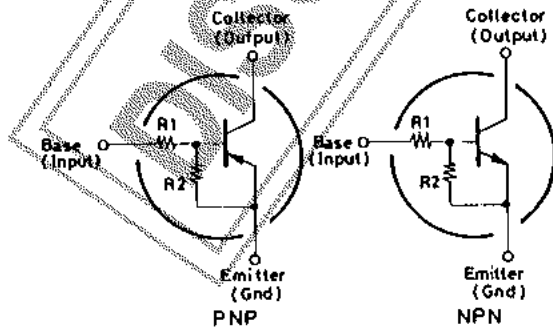
			unit
Collector to Base Voltage	V_{CBO}	(-)150	V
Collector to Emitter Voltage	V_{CEO}	(-)150	V
Emitter to Base Voltage	V_{EBO}	(-)10	V
Collector Current	I_C	(-)100	mA
Collector Current(Pulse)	I_{CP}	(-)200	mA
Collector Dissipation	P_C	300	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics/ $T_a=25^\circ\text{C}$

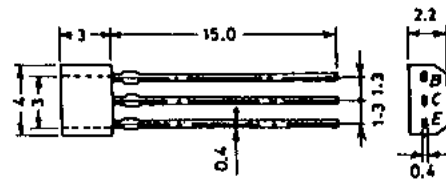
			min	typ	max	unit
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)140\text{V}, I_E=0$			(-)0.1	μA
Collector Cutoff Current	I_{CEO}	$V_{CE}=(-)140\text{V}, I_B=0$			(-)0.5	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)15\text{V}, I_C=0$	(-)140	(-)172	(-)100	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)15\text{V}, I_C=(-)5\text{mA}$	50			
Gain-bandwidth product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)5\text{mA}$		250 (200)		MHz
Output Capacitance	c_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		3.7 (5.5)		pF
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)5\text{mA}, I_B=(-)0.25\text{mA}$	(-)0.1	(-)0.3		V

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Electrical Connection



Case Outline 2033
(unit: mm)



B: Base
C: Collector
E: Emitter
SANYO: SPA

Specifications and information herein are subject to change without notice.

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			min	typ	max	unit
Collector to Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)50			V
Collector to Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)100\mu A, R_{BE}=\infty$	(-)50			V
Input Off Voltage	$V_{I(off)}$	$V_{CE}=(-)5V, I_C=(-)100\mu A$	(-)1.2	(-)1.6	(-)2.3	V
Input On Voltage	$V_{I(on)}$	$V_{CE}=(-)0.2V, I_C=(-)15mA$	(-)1.5	(-)3.1	(-)6.0	V
Input Resistance	R_1		32	46	60	k Ω
Input Resistance Ratio	R_1/R_2		1.8	2.0	2.2	-

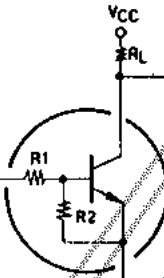
■ Sample Application Circuit

Input ON-state voltage: 6V or more

Input OFF-state voltage: 1.2V or less



INPUT



(For PNP, the polarity is reversed.)

